ON Semiconductor®

1N4728A - 1N4758A
Zener Diodes

Tolerance = 5%

DO-41 Glass case
COLOR BAND DENOTES CATHODE

Absolute Maximum Ratings * T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
P_D	Power Dissipation @ TL ≤ 50°C, Lead Length = 3/8”	1.0	W
	Derate above 50°C	6.67	mW/°C
T_J, T_{STG}	Operating and Storage Temperature Range	-65 to +200	°C

* These ratings are limiting values above which the serviceability of the diode may be impaired.

Electrical Characteristics T_a = 25°C unless otherwise noted

Device	V_Z (V) @ I_Z (Note 1)			Test Current I_Z (mA)	Max. Zener Impedance			Leakage Current		Non-Repetitive Peak Reverse Current I_{ZSM} (mA) (Note 2)
	Min.	Typ.	Max.		Z_Z @ I_Z (Ω)	Z_{ZK} @ I_{ZK} (Ω)	I_{ZK} (mA)	I_R (μA)	V_R (V)	
1N4728A	3.135	3.3	3.465	76	10	400	1	100	1	1380
1N4729A	3.42	3.6	3.78	69	10	400	1	100	1	1260
1N4730A	3.705	3.9	4.095	64	9	400	1	50	1	1190
1N4731A	4.085	4.3	4.515	58	9	400	1	10	1	1070
1N4732A	4.465	4.7	4.935	53	8	500	1	10	1	970
1N4733A	4.845	5.1	5.355	49	7	550	1	10	1	890
1N4734A	5.32	5.6	5.88	45	5	600	1	10	2	810
1N4735A	5.89	6.2	6.51	41	2	700	1	10	3	730
1N4736A	6.46	6.8	7.14	37	3.5	700	1	10	4	660
1N4737A	7.125	7.5	7.875	34	4	700	0.5	10	5	605
1N4738A	7.79	8.2	8.61	31	4.5	700	0.5	10	6	550
1N4739A	8.645	9.1	9.555	28	5	700	0.5	10	7	500
1N4740A	9.5	10	10.5	25	7	700	0.25	10	7.6	454
1N4741A	10.45	11	11.55	23	8	700	0.25	5	8.4	414
1N4742A	11.4	12	12.6	21	9	700	0.25	5	9.1	380

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Device	V_Z (V) @ I_Z (Note 1)			Test Current I_Z (mA)	Max. Zener Impedance			Leakage Current		Non-Repetitive Peak Reverse Current
	Min.	Typ.	Max.		Z_Z @ I_Z (Ω)	Z_{ZK} @ I_{ZK} (Ω)	I_{ZK} (mA)	I_R (μA)	V_R (V)	I_{ZSM} (mA) (Note 2)
1N4743A	12.35	13	13.65	19	10	700	0.25	5	9.9	344
1N4744A	14.25	15	15.75	17	14	700	0.25	5	11.4	304
1N4745A	15.2	16	16.8	15.5	16	700	0.25	5	12.2	285
1N4746A	17.1	18	18.9	14	20	750	0.25	5	13.7	250
1N4747A	19	20	21	12.5	22	750	0.25	5	15.2	225
1N4748A	20.9	22	23.1	11.5	23	750	0.25	5	16.7	205
1N4749A	22.8	24	25.2	10.5	25	750	0.25	5	18.2	190
1N4750A	25.65	27	28.35	9.5	35	750	0.25	5	20.6	170
1N4751A	28.5	30	31.5	8.5	40	1000	0.25	5	22.8	150
1N4752A	31.35	33	34.65	7.5	45	1000	0.25	5	25.1	135
1N4753A	34.2	36	37.8	7	50	1000	0.25	5	27.4	125
1N4754A	37.05	39	40.95	6.5	60	1000	0.25	5	29.7	115
1N4755A	40.85	43	45.15	6	70	1500	0.25	5	32.7	110
1N4756A	44.65	47	49.35	5.5	80	1500	0.25	5	35.8	95
1N4757A	48.45	51	53.55	5	95	1500	0.25	5	38.8	90
1N4758A	53.2	56	58.8	4.5	110	2000	0.25	5	42.6	80

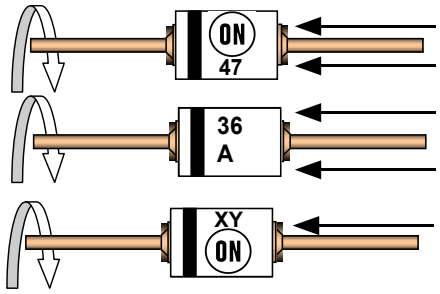
Notes:

1. Zener Voltage (V_Z)
   The zener voltage is measured with the device junction in the thermal equilibrium at the lead temperature (T_L) at 30°C ± 1°C and 3/8" lead length.
2. 2 Square wave Reverse Surge at 8.3 msec soak time.

Top Mark Information

Device	Line 1	Line 2	Line 3	Line 4	Line 5
1N4728A	LOGO	47	28	A	XY
1N4729A	LOGO	47	29	A	XY
1N4730A	LOGO	47	30	A	XY
1N4731A	LOGO	47	31	A	XY
1N4732A	LOGO	47	32	A	XY
1N4733A	LOGO	47	33	A	XY
1N4734A	LOGO	47	34	A	XY
1N4735A	LOGO	47	35	A	XY
1N4736A	LOGO	47	36	A	XY
1N4737A	LOGO	47	37	A	XY
1N4738A	LOGO	47	38	A	XY
1N4739A	LOGO	47	39	A	XY
1N4740A	LOGO	47	40	A	XY
1N4741A	LOGO	47	41	A	XY
1N4742A	LOGO	47	42	A	XY
1N4743A	LOGO	47	43	A	XY
1N4744A	LOGO	47	44	A	XY
1N4745A	LOGO	47	45	A	XY
1N4746A	LOGO	47	46	A	XY
1N4747A	LOGO	47	47	A	XY
1N4748A	LOGO	47	48	A	XY
1N4749A	LOGO	47	49	A	XY
1N4750A	LOGO	47	50	A	XY
1N4751A	LOGO	47	51	A	XY
1N4752A	LOGO	47	52	A	XY
1N4753A	LOGO	47	53	A	XY
1N4754A	LOGO	47	54	A	XY
1N4755A	LOGO	47	55	A	XY
1N4756A	LOGO	47	56	A	XY
1N4757A	LOGO	47	57	A	XY
1N4758A	LOGO	47	58	A	XY

Top Mark Information (Continued)



1st line: F - ON Semiconductor Logo

2nd line: Device Name - 3rd to 4th characters of device name for 1Nxx series
or 4th to 6th characters for BZXyy series

3rd line: Device Name - 5th to 6th characters of device name for 1Nxx series
or Voltage rating for BZXyy series

4th line: Device Name - 7th to 8th characters of device name for 1Nxx series
or Large Die identification only for BZXyy series

5th line: Date Code - Two Digit - Six Weeks Date Code

General Requirements:

1.0 Cathode Band

2.0 First Line: (ON) - ON Semiconductor Logo

3.0 Second Line: Device name - For 1Nxx series: 3rd to 4th characters of the device name.
For BZxx series: 4th to 6th characters of the device name.

4.0 Third Line: Device name - For 1Nxx series: 5th to 6th characters of the device name.
For BZXyy series: Voltage rating

5.0 Third Line: Device name - For 1Nxx series: 7th to 8th characters of the device name.
(the 8th character is the large die identification)

For BZXyy series: Large Die Identification character

6.0 Fourth Line: Date Code - Two Digit - Six Weeks Date Code
Where: X represents the last digit of the calendar year
Y represents the Six weeks numeric code

7.0 Devices shall be marked as required in the device specification (PID or ON Semiconductor Test Spec).

8.0 Maximum no. of marking lines: 5

9.0 Maximum no. of digits per line: 3

10.0 ON Semiconductor logo must be 20 % taller than the alphanumeric marking and should occupy the 2 characters of the specified line. 11.0 Marking Font: Arial (Except ON Semiconductor Logo)

12.0 First character of each marking line must be aligned vertically.

13.0 All device markings must be based on ON Semiconductor device specification.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
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Europe, Middle East and Africa Technical Support:
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Japan Customer Focus Center
Phone: 81−3−5817−1050

ON Semiconductor Website: **www.onsemi.com**

Order Literature: http://www.onsemi.com/orderlit

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